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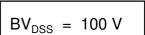
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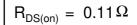
Advanced Power MOSFET

FEATURES

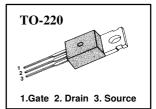
- Avalanche Rugged Technology
- Rugged Gate Oxide Technology
- Lower Input Capacitance
- Improved Gate Charge
- Extended Safe Operating Area
- 175°C Operating Temperature
- Lower Leakage Current : 10 μ A (Max.) @ V_{DS} = 100V
- Lower $R_{DS(ON)}$: 0.092 $\Omega(Typ.)$



IRF530A



 $I_D = 14 A$



Absolute Maximum Ratings

Symbol	Characteristic	Value	Units	
V _{DSS}	Drain-to-Source Voltage	100	V	
	Continuous Drain Current (T _C =25 °C)	14	^	
Ι _D	Continuous Drain Current (T _c =100 °C)	9.9	A	
I _{DM}	Drain Current-Pulsed ①	56	Α	
V _{GS}	Gate-to-Source Voltage	<u>+</u> 20	V	
E _{AS}	Single Pulsed Avalanche Energy (2)	261	mJ	
I _{AR}	Avalanche Current ()	14	Α	
E _{AR}	Repetitive Avalanche Energy ()	5.5	mJ	
dv/dt	Peak Diode Recovery dv/dt 3	6.5	V/ns	
	Total Power Dissipation (T _C =25°C)	55	W	
P _D	Linear Derating Factor	0.36	W/°C	
Operating Junction and		55 to 175		
T _J , T _{STG} Storage Temperature Range		- 55 to +175	°C	
Maximum Lead Temp. for Soldering		200		
Τ _L	Purposes, 1/8" from case for 5-seconds	300		

Thermal Resistance

Symbol	Characteristic	Тур.	Max.	Units
R _{θJC}	Junction-to-Case		2.74	
R _{θCS}	ecs Case-to-Sink			°C/W
R _{θJA}	Junction-to-Ambient		62.5	



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N-CHANNEL POWERMOSFET

Symbol	Characteristic	Min.	Тур.	Max.	Units	Test Condition
BV _{DSS}	Drain-Source Breakdown Voltage	100			V	V _{GS} =0V,I _D =250
$\Delta BV / \Delta T_J$	Breakdown Voltage Temp. Coeff.		0.11		V/ °C	I _D =250 μA See Fig 7
V _{GS(th)}	Gate Threshold Voltage	2.0		4.0	V	V_{DS} =5V,I _D =250 µA
	Gate-Source Leakage, Forward			100	nA	V _{GS} =20V
I _{GSS}	Gate-Source Leakage, Reverse			-100		V _{GS} =-20V
	Drain to Source Leakage Current			10	μA	V _{DS} =100V
I _{DSS}	Drain-to-Source Leakage Current			100		V_{DS} =80V, T_{C} =150°C
Б	Static Drain-Source		0.1	0.11	0	$V_{cc}=10V_{cc}=7A$
R _{DS(on)}	On-State Resistance				Ω	$V_{GS}=10V,I_{D}=7A$
9 _{fs}	Forward Transconductance		10.25		Ω	$V_{DS} = 40V, I_{D} = 7A$ (4)
C _{iss}	Input Capacitance		610	790		\/0\/ \/25\/ f1MHz
C _{oss}	Output Capacitance		150	175	pF V _{GS} =0V,V _{DS} =25V,f =1N <i>See Fig 5</i>	
C _{rss}	Reverse Transfer Capacitance		62	72		See Fig 5
t _{d(on)}	Turn-On Delay Time		13	40		V _{DD} =50V,I _D =14A,
t _r	Rise Time		14	40	20	$R_{G}=12\Omega$
t _{d(off)}	Turn-Off Delay Time		55	110	ns	See Fig 13 4 5
t _f	Fall Time		36	80		
Qg	Total Gate Charge		27	36		$V_{DS} = 80V, V_{GS} = 10V,$
Q _{gs}	Gate-Source Charge		4.5		nC	I _D =14A
Q _{gd}	Gate-Drain("Miller") Charge		12.8		1	See Fig 6 & Fig 12 $@$

Electrical Characteristics ($T_C=25$ °C unless otherwise specified)

Source-Drain Diode Ratings and Characteristics

Symbol	Characteristic		Min.	Тур.	Max.	Units	Test Condition
ا _s	Continuous Source Current				14	^	Integral reverse pn-diode
I _{SM}	Pulsed-Source Current	D			56	А	in the MOSFET
V _{SD}	Diode Forward Voltage	9			1.5	V	T _J =25°C,I _S =14A,V _{GS} =0V
t _{rr}	Reverse Recovery Time			109		ns	T _J =25°C,I _F =14A
Q _{rr}	Reverse Recovery Charge			0.41		¥C	di _F /dt=100A/µs ④

Notes;

- () Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature
- 2 L=2mH, I_{AS} =14A, V_{DD} =25V, R_{G} =27 Ω , Starting T_{J} =25 °C

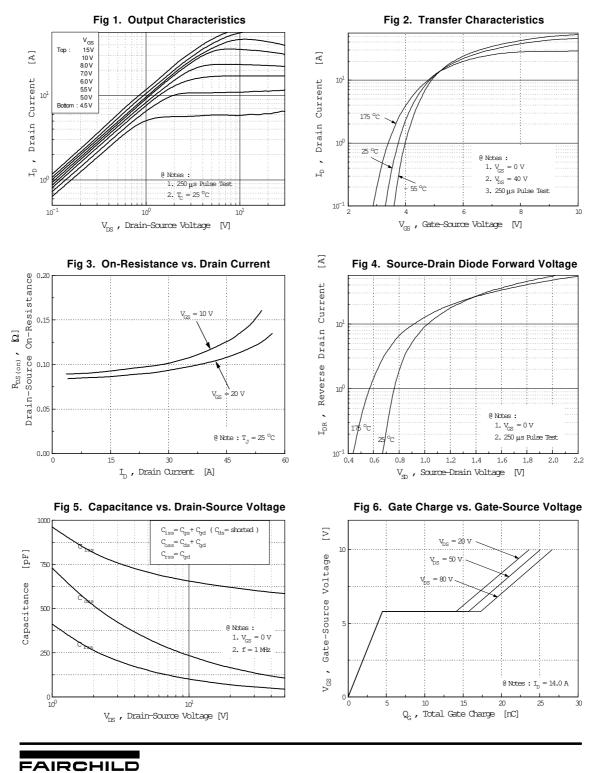
- 5 Essentially Independent of Operating Temperature

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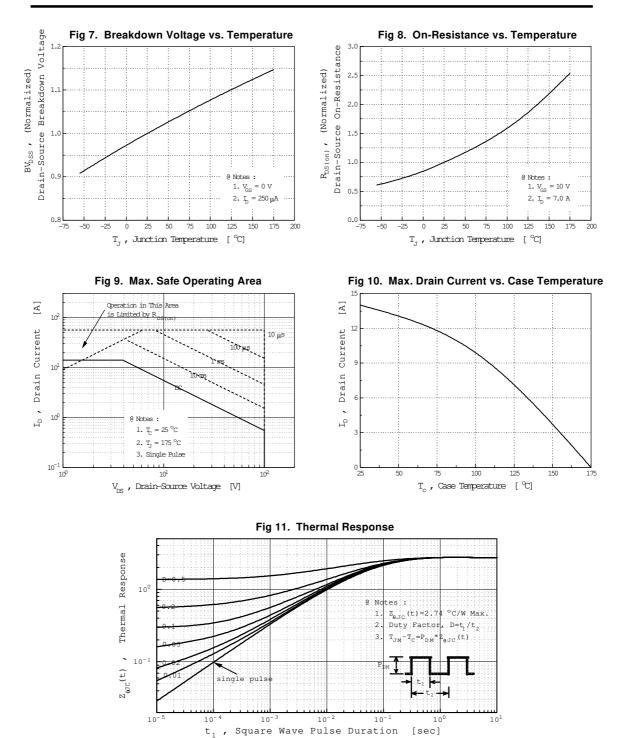
IRF530A



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IRF530A

N-CHANNEL POWER MOSFET



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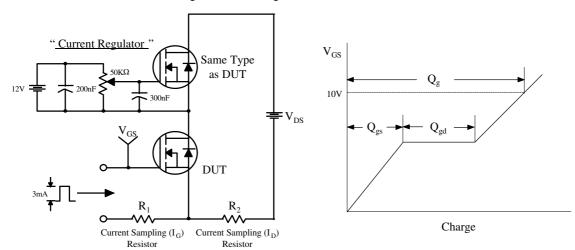


Fig 12. Gate Charge Test Circuit & Waveform



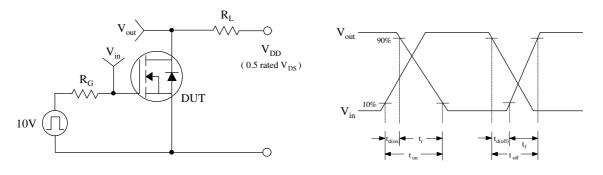
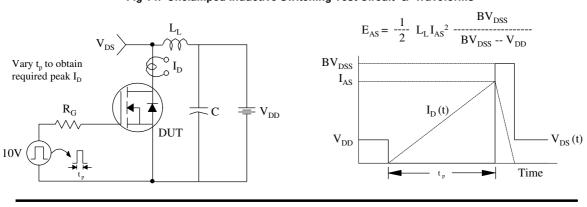


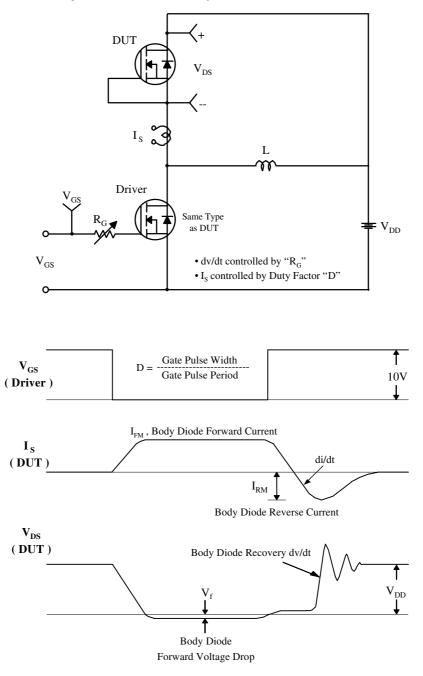
Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms

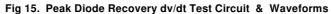




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